SN65LBC173, SN75LBC173 QUADRUPLE LOW-POWER DIFFERENTIAL LINE RECEIVERS

SLLS170E - OCTOBER 1993 - REVISED AUGUST 2000

- Meets or Exceeds the Requirements of ANSI Standards EIA/TIA-422-B, EIA/TIA-423-B, RS-485, and ITU Recommendations V.10 and V.11.
- Designed to Operate With Pulse Durations as Short as 20 ns
- Designed for Multipoint Bus Transmission on Long Bus Lines in Noisy Environments
- Input Sensitivity . . . ±200 mV
- Low-Power Consumption . . . 20 mA Max
- Open-Circuit Fail-Safe Design
- Pin Compatible With SN75173 and AM26LS32

DORNPACKAGE (TOP VIEW) 16 V_{CC} 1B 15 4B 1A [3 14 4A 1Y 📙 G [13 4Y 12 G 5 2Y 6 11 T 3Y 2A 2B 🛚 10 3A 9**∏** 3B 8 GND l

description

The SN65LBC173 and SN75LBC173 are monolithic quadruple differential line receivers with 3-state outputs. Both are designed to meet the requirements of the ANSI standards EIA/TIA-422-B, EIA/TIA-423-B, RS-485, and ITU Recommendations V.10 and V.11. The devices are optimized for balanced multipoint bus transmission at data rates up to and exceeding 10 million bits per second. The four receivers share two ORed enable inputs, one active when high, the other active when low.

Each receiver features high input impedance, input hysteresis for increased noise immunity, and input sensitivity of ± 200 mV over a common-mode input voltage range of 12 V to -7 V. Fail-safe design ensures that if the inputs are open circuited, the output is always high. Both devices are designed using the Texas Instruments proprietary LinBiCMOSTM technology that provides low power consumption, high switching speeds, and robustness.

These devices offer optimum performance when used with the SN75LBC172 or SN75LBC174 quadruple line drivers. The SN65LBC173 and SN75LBC173 are available in the 16-pin DIP (N) and SOIC (D) packages.

The SN65LBC173 is characterized over the industrial temperature range of –40°C to 85°C. The SN75LBC173 is characterized for operation over the commercial temperature range of 0°C to 70°C.

FUNCTION TABLE (each receiver)

DIFFERENTIAL INPUTS A-B	ENAI	BLES	OUTPUT
	G	G	Y
V _{ID} ≥ 0.2 V	H	X	H
	X	L	H
-0.2 V < V _{ID} < 0.2 V	H X	X L	?
V _{ID} ≤ −0.2 V	H	X	L
	X	L	L
X	L	Н	Z
Open Circuit	H	X	H
	X	L	H

H = high level, L = low level, X = irrelevant, Z = high impedance (off), ? = indeterminate

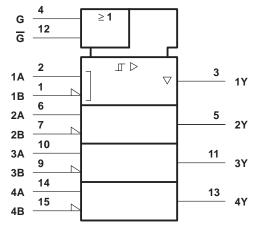


Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

LinBiCMOS is a trademark of Texas Instruments.

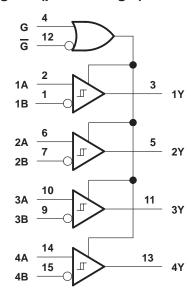


logic symbol†

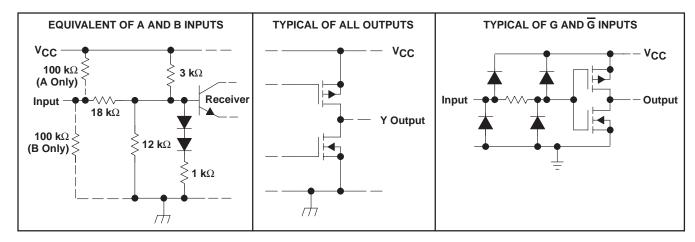


[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)



schematics of inputs and outputs



SN65LBC173, SN75LBC173 QUADRUPLE LOW-POWER DIFFERENTIAL LINE RECEIVERS

SLLS170E - OCTOBER 1993 - REVISED AUGUST 2000

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage range, V _{CC} (see Note 1)		–0.3 V to 7 V
Input voltage, V _I (A or B inputs)		$\dots \dots \pm 25 \ V$
Differential input voltage, V _{ID} (see Note 2))	$\dots \dots \pm 25 \ V$
Voltage range at Y, G, G		$-0.3 \text{ V to V}_{CC} + 0.5 \text{ V}$
Continuous total dissipation		
Operating free-air temperature range, T _A :	SN65LBC173	40°C to 85°C
	SN75LBC173	0°C to 70°C
Storage temperature range, T _{stq}		65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from		

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

2. Differential input voltage is measured at the noninverting input with respect to the corresponding inverting input.

DISSIPATION RATING TABLE

	$T_A = 25^{\circ}C$ POWER RA	ATING POWER RATING
• • • • • • • • • • • • • • • • • • • •		
	• • • • • • • • • • • • • • • • • • • •	

recommended operating conditions

				MIN	NOM	MAX	UNIT
Supply voltage, V _{CC}						5.25	V
Common-mode input voltage, V _{IC}				-7		12	V
Differential input voltage, V _{ID}						±6	V
High-level input voltage, VIH	0 :	G inputs					V
Low-level input voltage, V _{IL}	G Inpu					8.0	V
High-level output current, IOH						-8	mA
Low-level output current, IOL	Low-level output current, IOL					8	mA
On another transmission to an article T	SN65L	SN65LBC173		-40		85	°C
Operating free-air temperature, T _A	SN75L	SN75LBC173				70	C

NOTES: 1. All voltage values are with respect to GND.

SN65LBC173, SN75LBC173 QUADRUPLE LOW-POWER DIFFERENTIAL LINE RECEIVERS

SLLS170E - OCTOBER 1993 - REVISED AUGUST 2000

electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER			TI	MIN	TYP†	MAX	UNIT		
V _{IT+}	Positive-going input thres	shold voltage	$I_{O} = -8 \text{ mA}$					0.2	V
VIT-	Negative-going input thre	shold voltage	I _O = 8 mA			-0.2			V
V _{hys}	Hysteresis voltage (VIT+	VIT _)					45		mV
VIK	Enable input clamp volta	ge	I _I = –18 mA				-0.9	-1.5	V
Vон	High-level output voltage		V _{ID} = 200 mV,	I _{OH} = -8 m/	A	3.5	4.5		V
VOL	Low-level output voltage		$V_{ID} = -200 \text{ mV},$	I _{OL} = 8 mA			0.3	0.5	V
loz	OZ High-impedance-state output current		$V_O = 0 V \text{ to } V_{CC}$					±20	μΑ
			V _{IH} = 12 V,	V _{CC} = 5 V,	Other inputs at 0 V		0.7	1	
١.	Bus input current	A or B inputs	V _{IH} = 12 V,	$V_{CC} = 0 V$	Other inputs at 0 V		0.8	1	
l _l			$V_{IH} = -7 V$,	V _{CC} = 5 V,	Other inputs at 0 V		-0.5	-0.8	mA
			$V_{IH} = -7 V$,	$V_{CC} = 0 V$	Other inputs at 0 V		-0.4	-0.8	
lн	High-level input current		V _{IH} = 5 V					±20	μΑ
IIL	IL Low-level input current		V _{IL} = 0 V					-20	μΑ
los	OS Short-circuit output current		V _O = 0				-80	-120	mA
la a	Cumply aurrent	_	Outputs enabled,	I _O = 0,	V _{ID} = 5 V		11	20	A
ICC	ICC Supply current		Outputs disabled				0.9	1.4	mA

 $^{^{\}dagger}$ All typical values are at V_{CC} = 5 V and T_A = 25°C.

switching characteristics, V_{CC} = 5 V, C_L = 15 pF, T_A = 25°C

	PARAMETER	TEST CONDITIONS		MIN	TYP	MAX	UNIT
tPHL	Propagation delay time, high- to low-level output	V- 45V4545V Coo Figure		11	22	30	ns
tPLH	Propagation delay time, low- to high-level output	$V_{ID} = -1.5 \text{ V to } 1.5 \text{ V},$ See Figure	9 1	11	22	30	ns
^t PZH	Output enable time to high level	See Figure 2			17	30	ns
tpzL	Output enable time to low level	See Figure 3			18	30	ns
tPHZ	Output disable time from high level	See Figure 2			35	45	ns
tPLZ	Output disable time from low level	See Figure 3			25	40	ns
t _{sk(p)}	Pulse skew (tpHL - tpLH)	See Figure 2			0.5	6	ns
t _t	Transition time	See Figure 1			5	10	ns

PARAMETER MEASUREMENT INFORMATION

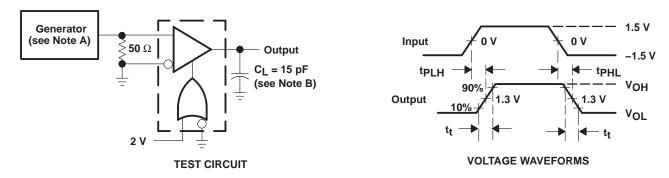
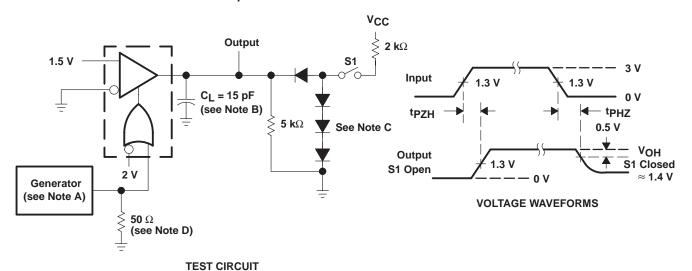


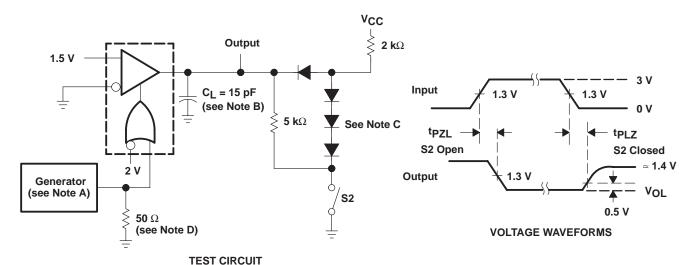
Figure 1. tpd and tt Test Circuit and Voltage Waveforms



- NOTES: A. The input pulse is supplied by a generator having the following characteristics: PRR = 1 MHz, duty cycle = 50%, $t_{\Gamma} \le 6$ ns, $t_{f} \le 6$ ns, $Z_{O} = 50$ Ω .
 - B. C_L includes probe and jig capacitance.
 - C. All diodes are 1N916 or equivalent.
 - D. To test the active-low enable \overline{G} , ground G and apply an inverted input waveform to \overline{G} .

Figure 2. tpHZ and tpZH Test Circuit and Voltage Waveforms

PARAMETER MEASUREMENT INFORMATION



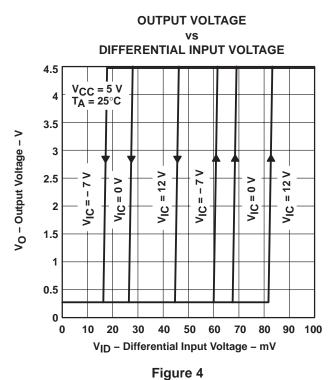
NOTES: A. The input pulse is supplied by a generator having the following characteristics: PRR = 1 MHz, duty cycle = 50%, $t_{\Gamma} \le 6$ ns, $t_$

- B. C_L includes probe and jig capacitance.
- C. All diodes are 1N916 or equivalent.
- D. To test the active-low enable \overline{G} , ground G and apply an inverted input waveform to \overline{G} .

Figure 3. tpzL and tpLZ Test Circuit and Voltage Waveforms

TYPICAL CHARACTERISTICS

5.5



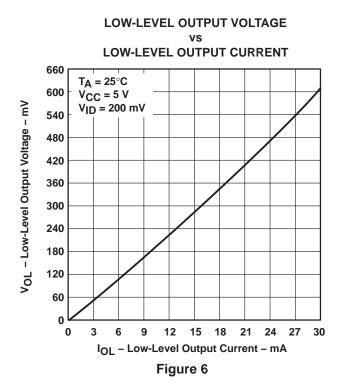
5 V_{CC} = 5.25 V VOH - High-Level Output Voltage - V 4.5 $V_{CC} = 5 V$ 3.5 $V_{CC} = 4.75 V$ 3 2.5 2 1.5 1 $V_{ID} = 0.2 V$ 0.5 $T_A = 25^{\circ}C$ 0 0 -8 -12 -16 -20 -24 -28 -32 -36 -40 IOH - High-Level Output Current - mA

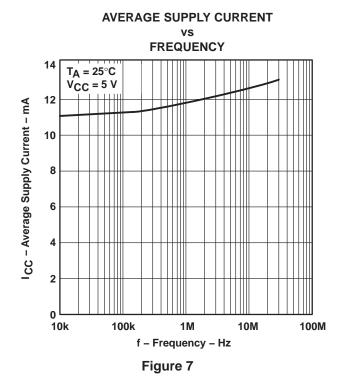
HIGH-LEVEL OUTPUT VOLTAGE

HIGH-LEVEL OUTPUT CURRENT

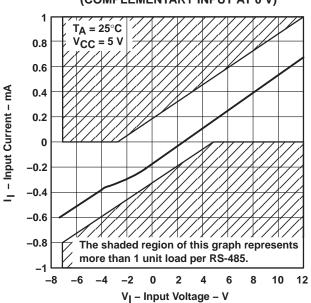
Figure 5

TYPICAL CHARACTERISTICS









vs FREE-AIR TEMPERATURE 24.5 V_CC = 5 V $C_L = 15 pF$ $V_{10} = \pm 1.5 \text{ V}$ pd - Propagation Delay Time - ns 24 ^tPHL 23.5 23 **tPLH** 22.5 22 -20 100 -40 40 60 80 T_A - Free-Air Temperature - °C

Figure 9

PROPAGATION DELAY TIME

Figure 8



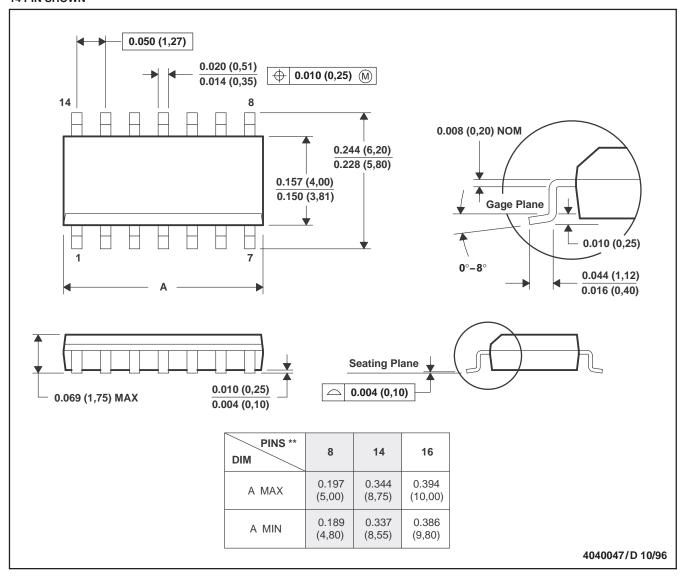
SLLS170E - OCTOBER 1993 - REVISED AUGUST 2000

MECHANICAL DATA

D (R-PDSO-G**)

14 PIN SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0.006 (0,15).

D. Falls within JEDEC MS-012

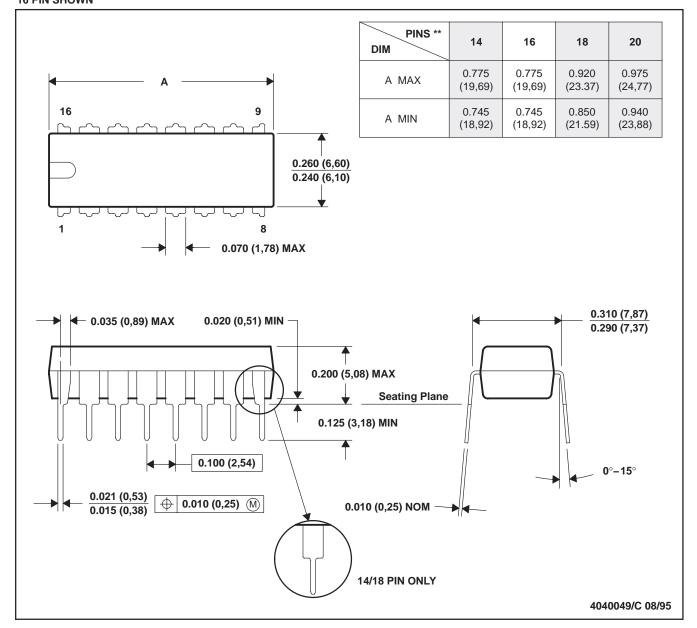
SLLS170E - OCTOBER 1993 - REVISED AUGUST 2000

MECHANICAL DATA

N (R-PDIP-T**)

16 PIN SHOWN

PLASTIC DUAL-IN-LINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MS-001 (20 pin package is shorter then MS-001.)

PACKAGE OPTION ADDENDUM



i.com 18-Sep-2008

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
SN65LBC173D	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65LBC173DG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65LBC173DR	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65LBC173DRG4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65LBC173N	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
SN65LBC173NE4	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
SN75LBC173D	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75LBC173DG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75LBC173DR	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75LBC173DRG4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75LBC173N	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
SN75LBC173NE4	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.



PACKAGE OPTION ADDENDUM

18-Sep-2008

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF SN75LBC173:

• Military: SN55LBC173

NOTE: Qualified Version Definitions:

• Military - QML certified for Military and Defense Applications



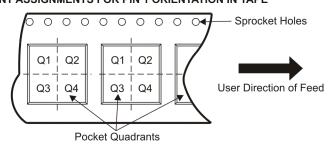
TAPE AND REEL INFORMATION



TAPE DIMENSIONS + K0 - P1 - B0 W Cavity - A0 -

	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN65LBC173DR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
SN65LBC173DR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
SN75LBC173DR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
SN75LBC173DR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1





*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN65LBC173DR	SOIC	D	16	2500	333.2	345.9	28.6
SN65LBC173DR	SOIC	D	16	2500	346.0	346.0	33.0
SN75LBC173DR	SOIC	D	16	2500	346.0	346.0	33.0
SN75LBC173DR	SOIC	D	16	2500	333.2	345.9	28.6

IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, modifications, enhancements, improvements, and other changes to its products and services at any time and to discontinue any product or service without notice. Customers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All products are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its hardware products to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by government requirements, testing of all parameters of each product is not necessarily performed.

TI assumes no liability for applications assistance or customer product design. Customers are responsible for their products and applications using TI components. To minimize the risks associated with customer products and applications, customers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any TI patent right, copyright, mask work right, or other TI intellectual property right relating to any combination, machine, or process in which TI products or services are used. Information published by TI regarding third-party products or services does not constitute a license from TI to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. Reproduction of this information with alteration is an unfair and deceptive business practice. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions

Resale of TI products or services with statements different from or beyond the parameters stated by TI for that product or service voids all express and any implied warranties for the associated TI product or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

TI products are not authorized for use in safety-critical applications (such as life support) where a failure of the TI product would reasonably be expected to cause severe personal injury or death, unless officers of the parties have executed an agreement specifically governing such use. Buyers represent that they have all necessary expertise in the safety and regulatory ramifications of their applications, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of TI products in such safety-critical applications, notwithstanding any applications-related information or support that may be provided by TI. Further, Buyers must fully indemnify TI and its representatives against any damages arising out of the use of TI products in such safety-critical applications.

TI products are neither designed nor intended for use in military/aerospace applications or environments unless the TI products are specifically designated by TI as military-grade or "enhanced plastic." Only products designated by TI as military-grade meet military specifications. Buyers acknowledge and agree that any such use of TI products which TI has not designated as military-grade is solely at the Buyer's risk, and that they are solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI products are neither designed nor intended for use in automotive applications or environments unless the specific TI products are designated by TI as compliant with ISO/TS 16949 requirements. Buyers acknowledge and agree that, if they use any non-designated products in automotive applications, TI will not be responsible for any failure to meet such requirements.

Following are URLs where you can obtain information on other Texas Instruments products and application solutions:

Products Amplifiers amplifier.ti.com Data Converters dataconverter.ti.com DSP dsp.ti.com Clocks and Timers www.ti.com/clocks Interface interface.ti.com Logic logic.ti.com Power Mgmt power.ti.com Microcontrollers microcontroller.ti.com www.ti-rfid.com RF/IF and ZigBee® Solutions www.ti.com/lprf

Applications	
Audio	www.ti.com/audio
Automotive	www.ti.com/automotive
Broadband	www.ti.com/broadband
Digital Control	www.ti.com/digitalcontrol
Medical	www.ti.com/medical
Military	www.ti.com/military
Optical Networking	www.ti.com/opticalnetwork
Security	www.ti.com/security
Telephony	www.ti.com/telephony
Video & Imaging	www.ti.com/video
Wireless	www.ti.com/wireless

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2008, Texas Instruments Incorporated